

Citations for Target : **SiC**

Pub. Year	Authors, Title, Journal Citation and Comments	Citation Numb
1966	Makarov, V. V. Petrov, N. N. 'Penetration of 2 to 11 keV Lithium Ions into Silicon Carbide Single Crystals' <i>Izv. Akad. Nauk. Sssr Ser. Fiz., 30, 890-91 (1966). [Engl. Trans. Bull. Acad. Sci. Ussr, Phys. Ser., 30, 925-26 (1966).</i> <i>Comment : R. 2-11 keV Li -> SiC (Cryst.)</i>	1966-Maka 0767
1967	Makarov, V. V. Petrov, N. N. 'Penetration of Light Atomic and Molecular Ions into SiC Single Crystals' <i>Fiz. Tverd. Tela, 8, 3723-25 (1966) [Engl. Trans. Sov. Phys. Solid State, 8, 2993-84 (1967)]</i> <i>Comment : R. 4-20 keV H, H2, H3, D, D2, D3, He -> SiC</i>	1967-Maka 0288
1970	Clark, G. J. Morgan, D. V. Poate, J. M. 'Energy Loss of Channeled Protons in the MeV Region, in D' <i>W. Palmer, M. W. Thompson, P. D. Townsend: Atomic Collision Phenomena in Solids. North-Holland, Amsterdam, P. 388-99 (1970)</i> <i>Comment : S, dS. (4-8 MeV) H -> SiC, W, Fe, Ge, Mo, NaCl, MgO (All Targets Cryst.)</i>	1970-Clar 0391
1971	Makarov, V. V. Petrov, N. N. 'Investigation of the Slowing Down of Positive Ions in Silicon Carbide' <i>Fiz. Tekh. Poluprovodnikov, 5, 510-13 (1971). [Engl. Trans. Sov. Phys. Semicond., 5, 447-49 (1971).</i> <i>Comment : R. Eta(Epsilon). 1-20 keV H, Li, 2-20 keV D, He, Na, 3-20 keV K -> SiC</i>	1971-Maka 0682
1973	Comas, J. Lucke, W. Addamiano, A. 'Ion Implanted Al Concentration Profiles in Unannealed and Annealed 6H-SiC' <i>Bull. Am. Phys. Soc., 18, 606a (1973)</i> <i>Comment : R, dR. 60 keV Al -> SiC</i>	1973-Coma 0449
1973	Dunning, K. L. Comas, J. Hubler, G. K. 'Depth Profiles of Aluminum Implanted into SiC. Nuclear Resonance Method.' <i>Bull. Am. Phys. Soc., 18, 606b (1973)</i> <i>Comment : R,dR. 60 keV Al -> SiC</i>	1973-Dunn 0450
1973	Dunning, K. L. Hubsher, G. K. Comas, J. Lucks, W. H. Hughes, H. L. 'Depth Profiles of Aluminum and Sodium Near Surfaces: Nuclear Resonance Method' <i>Thin Solid Films, 19, 145-156 (1973)</i> <i>Comment : R, dR. 60 keV Al -> SiC, 20, 60 keV Na -> SiO2</i>	1973-Dunn2 0621
1975	Lucke, W. Comas, J. Hubler, G. Dunning, K. 'Effect of Annealing on Profiles of Aluminum Implanted into Silicon Carbide' <i>J. Appl. Phys., 46, 994-97 (1975)</i> <i>Comment : R. 60 keV Al -> SiC</i>	1975-Luck 0528

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1987	Kido, Y. 'Energy Straggling for Fast Proton Beams Passing through Solid Materials' <i>Nucl. Inst. Methods, B24/25, 347-352 (1987)</i> <i>Comment : H (300-1000 keV) -> C, Ti, TiC, Si, SiC, SiO2, TiO2</i>	1987-Kido
		1664